imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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MPS6724, MPS6725

One Watt Darlington Transistors

NPN Silicon

Features

Pb–Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage MPS6724 MPS6725	V _{CEO}	40 50	Vdc
Collector – Base Voltage MPS6724 MPS6725	V _{CBO}	50 60	Vdc
Emitter-Base Voltage	V _{EBO}	12	Vdc
Collector Current – Continuous	Ι _C	1000	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	1.0 8.0	W mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	2.5 20	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

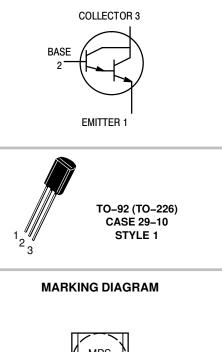
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

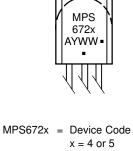
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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	x = 4 or 5	
А	 Assembly Location 	
Y	= Year	
WW	 Work Week 	
•	= Pb–Free Package	
lote: Microdo	t may be in either locatio	r

(No n) ιy

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

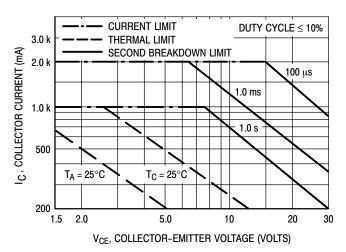
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MPS6724, MPS6725

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 1) $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	MPS6724 MPS6725	V _{(BR)CES}	40 50		Vdc
Collector – Base Breakdown Voltage $(I_C = 1.0 \ \mu Adc, I_E = 0)$	MPS6724 MPS6725	V _{(BR)CBO}	50 60		Vdc
Emitter – Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$		V _{(BR)EBO}	12	-	Vdc
Collector Cutoff Current $(V_{CB} = 30 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 40 \text{ Vdc}, I_E = 0)$	MPS6724 MPS6725	I _{CBO}		100 100	nAdc
Emitter Cutoff Current ($V_{EB} = 10$ Vdc, $I_C = 0$)		I _{EBO}	-	100	nAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain ($I_C = 200 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 1000 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$)		h _{FE}	25,000 4,000	40,000	-
Collector – Emitter Saturation Voltage $(I_C = 1000 \text{ mAdc}, I_B = 2.0 \text{ mAdc})$		V _{CE(sat)}	-	1.5	Vdc
Base – Emitter On Voltage ($I_C = 1000 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$)		V _{BE(on)}	-	2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain – Bandwidth Product $(I_C = 200 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz})$		f _T	100	1000	MHz
Collector-Base Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$		C _{cb}	-	10	pF
Collector–Base Capacitance		C _{cb}	-	10	

1. Pulse Test: Pulse Width \leq 300 µs; Duty Cycle \leq 2.0%.



TYPICAL CHARACTERISTICS

Figure 1. Active Region — Safe Operating Area

MPS6724, MPS6725

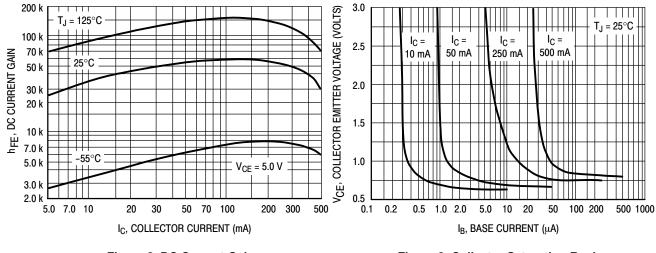




Figure 3. Collector Saturation Region

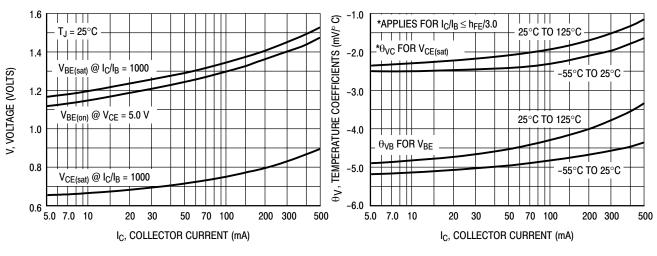
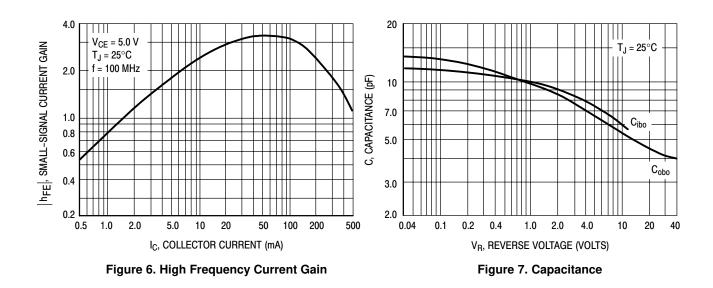


Figure 4. "ON" Voltages

Figure 5. Temperature Coefficients



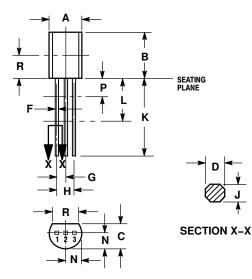
ORDERING INFORMATION

Device	Package	Shipping [†]
MPS6724	TO-92	
MPS6724G	TO–92 (Pb–Free)	5000 Units / Bulk
MPS6725	TO-92	
MPS6725G	TO–92 (Pb–Free)	5000 Units / Bulk
MPS6724RLRA	TO-92	
MPS6724RLRAG	TO–92 (Pb–Free)	2000 Units / Tape & Reel
MPS6725RLRP	TO-92	
MPS6725RLRPG	TO–92 (Pb–Free)	2000 Units / Tape & Ammo Box

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-10 ISSUE AL



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- 2. CONTROLLING DIMENSION: INCH.
- 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- I. DIMENSION F APPLIES BETWEEN P AND L DIMENSIONS D AND J APPLY BETWEEN L AND K MIMIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.457	0.533
F	0.016	0.019	0.407	0.482
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
L	0.018	0.024	0.46	0.61
Κ	0.500		12.70	
Г	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.135		3.43	

STYLE 1: PIN 1. EMITTER

2. BASE 3. COLLECTOR

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